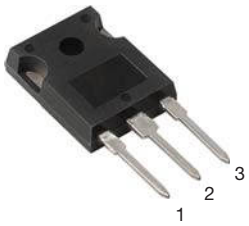
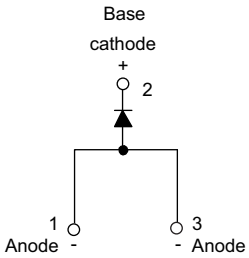
Fast Soft Recovery Rectifier Diode, 80 A



TO-247AC



FEATURES

- 150 °C max. operating junction temperature
- Low forward voltage drop and short reverse recovery time
- Designed and qualified according to JEDEC®-JESD47
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

Pb
e3
RoHS COMPLIANT
HALOGEN FREE Available

APPLICATIONS

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

DESCRIPTION

The VS-80APF0... soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

PRODUCT SUMMARY	
Package	TO-247AC
$I_{F(AV)}$	80 A
V_R	200 V, 400 V, 600 V
V_F at I_F	1.25 V
I_{FSM}	1000 A
t_{rr}	70 ns
T_J max.	150 °C
Diode variation	Single die
Snap factor	0.5

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
V_{RRM}		200 to 600	V
$I_{F(AV)}$	Sinusoidal waveform	80	A
I_{FSM}		1000	
t_{rr}	1 A, - 100 A/µs	70	ns
V_F	40 A, T_J = 25 °C	1.1	V
T_J	Range	-40 to 150	°C

VOLTAGE RATINGS			
PART NUMBER	V_{RRM}, MAXIMUM PEAK REVERSE VOLTAGE V	V_{RSM}, MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} AT 150 °C mA
VS-80APF02PbF, VS-80APF02-M3	200	300	17
VS-80APF04PbF, VS-80APF04-M3	400	500	
VS-80APF06PbF, VS-80APF06-M3	600	700	

ABSOLUTE MAXIMUM RATINGS

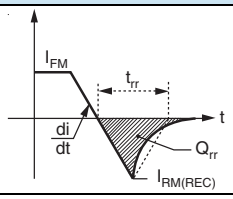
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	T_C = 95 °C, 180° conduction half sine wave	80	A
Maximum peak one cycle non-repetitive surge current	I_{FSM}	10 ms sine pulse, rated V_{RRM} applied	850	A
		10 ms sine pulse, no voltage reapplied	1000	A
Maximum I^2t for fusing	I^2t	10 ms sine pulse, rated V_{RRM} applied	3610	A^2s
		10 ms sine pulse, no voltage reapplied	5100	A^2s
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	t = 0.1 ms to 10 ms, no voltage reapplied	51 000	$A^2\sqrt{s}$

ELECTRICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V_{FM}	80 A, T_J = 25 °C		1.25	V
Forward slope resistance	r_t	T_J = 150 °C		3.5	mΩ
Threshold voltage	$V_{F(TO)}$			0.85	V
Maximum reverse leakage current	I_{RM}	T_J = 25 °C	V_R = Rated V_{RRM}	0.1	mA
		T_J = 150 °C		17	

RECOVERY CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Reverse recovery time	t_{rr}	I_F at 40 Apk 25 A/µs 25 °C	190	ns
Reverse recovery current	I_{rr}		3.4	A
Reverse recovery charge	Q_{rr}		0.5	µC
Snap factor	S		0.5	



THERMAL - MECHANICAL SPECIFICATIONS

PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T_J, T_{Stg}		-40 to 150	°C
Maximum thermal resistance, junction to case		R_{thJC}	DC operation	0.35	°C/W
Maximum thermal resistance, junction to ambient		R_{thJA}		40	
Typical thermal resistance, case to heatsink		R_{thCS}	Mounting surface, smooth and greased	0.2	
Approximate weight				6	g
				0.21	oz.
Mounting torque	minimum			6 (5)	kgf · cm (lbf · in)
	maximum			12 (10)	
Marking device			Case style TO-247AC	80APF02	
				80APF04	
				80APF06	

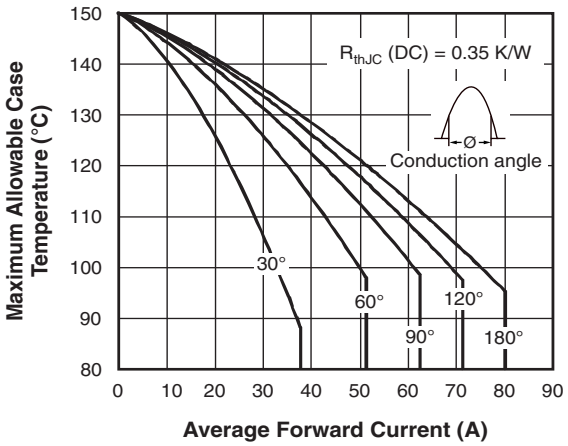


Fig. 1 - Current Rating Characteristics

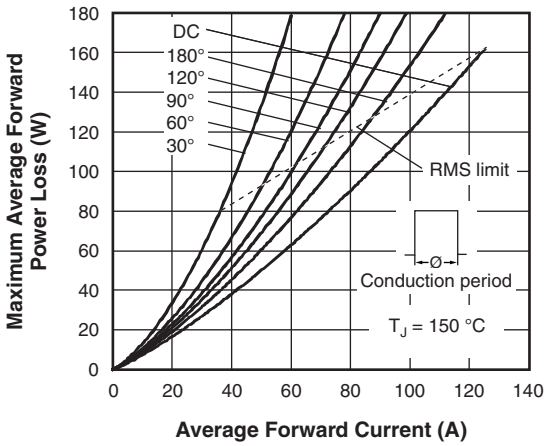


Fig. 4 - Forward Power Loss Characteristics

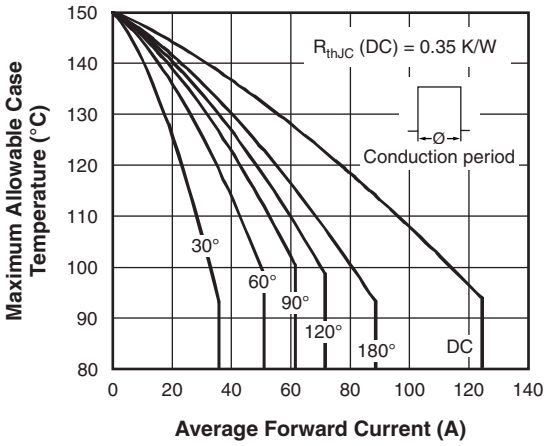


Fig. 2 - Current Rating Characteristics

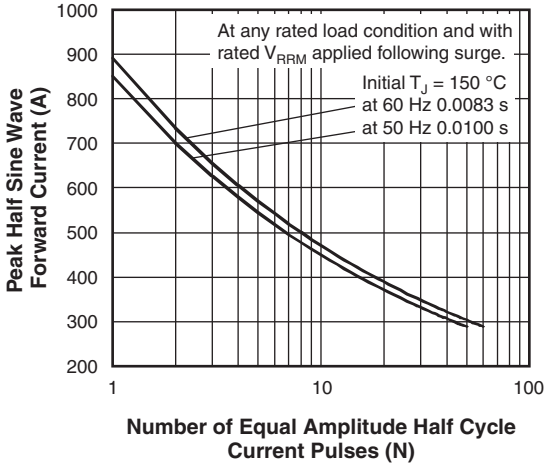


Fig. 5 - Maximum Non-Repetitive Surge Current

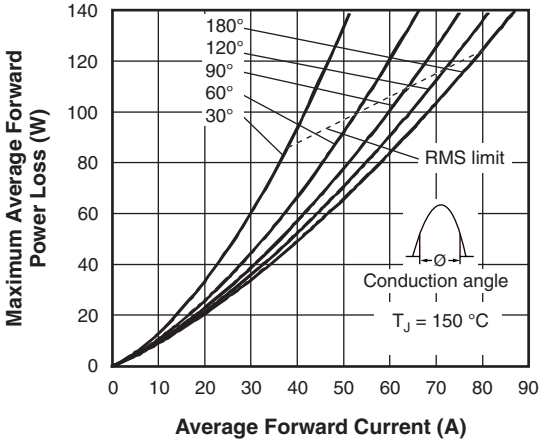


Fig. 3 - Forward Power Loss Characteristics

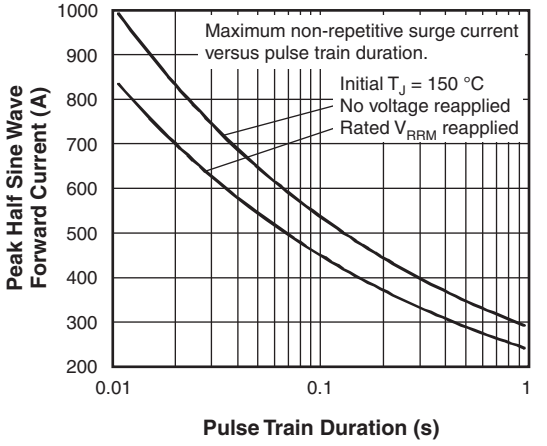


Fig. 6 - Maximum Non-Repetitive Surge Current

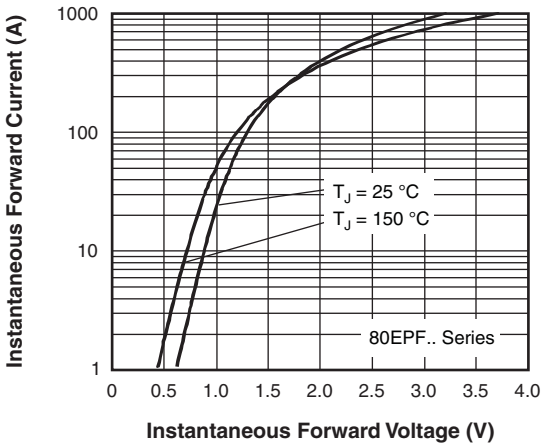


Fig. 7 - Forward Voltage Drop Characteristics

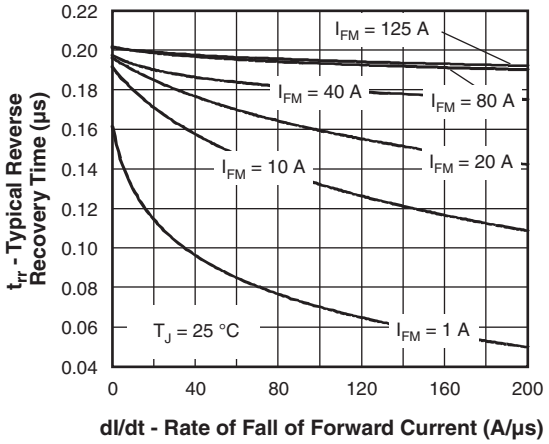


Fig. 8 - Recovery Time Characteristics, T_J = 25 °C

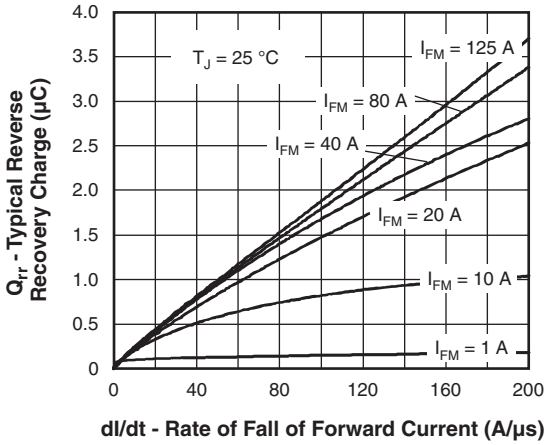


Fig. 10 - Recovery Charge Characteristics, T_J = 25 °C

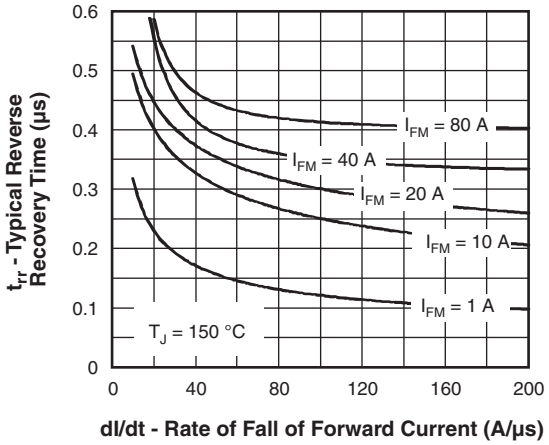


Fig. 9 - Recovery Time Characteristics, T_J = 150 °C

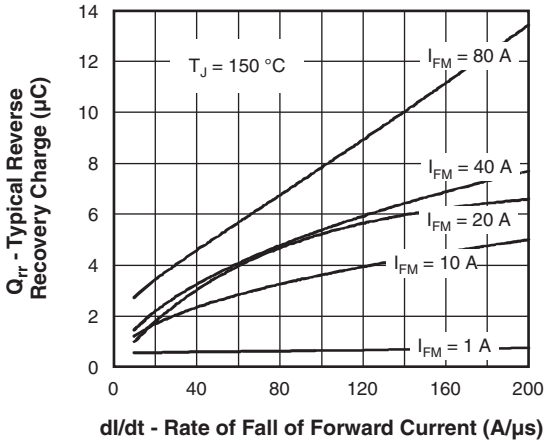


Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C

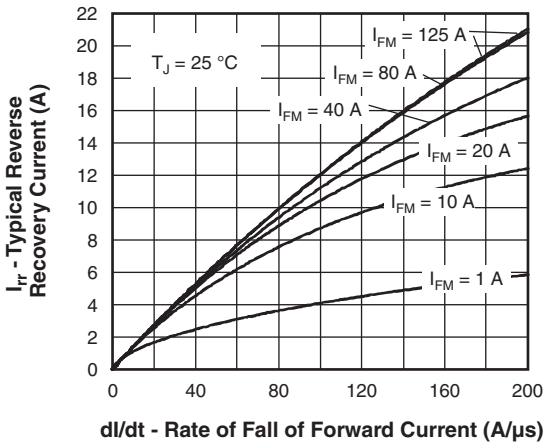


Fig. 12 - Recovery Current Characteristics, T_J = 25 °C

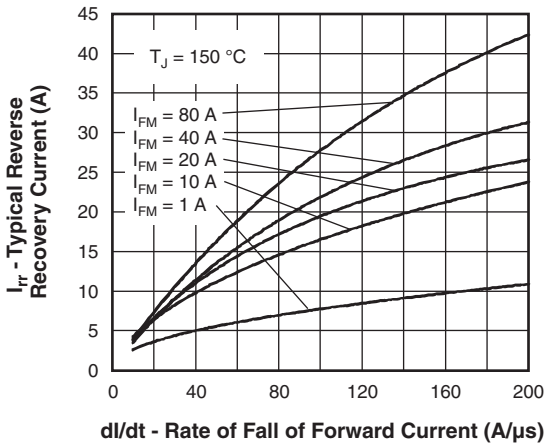


Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

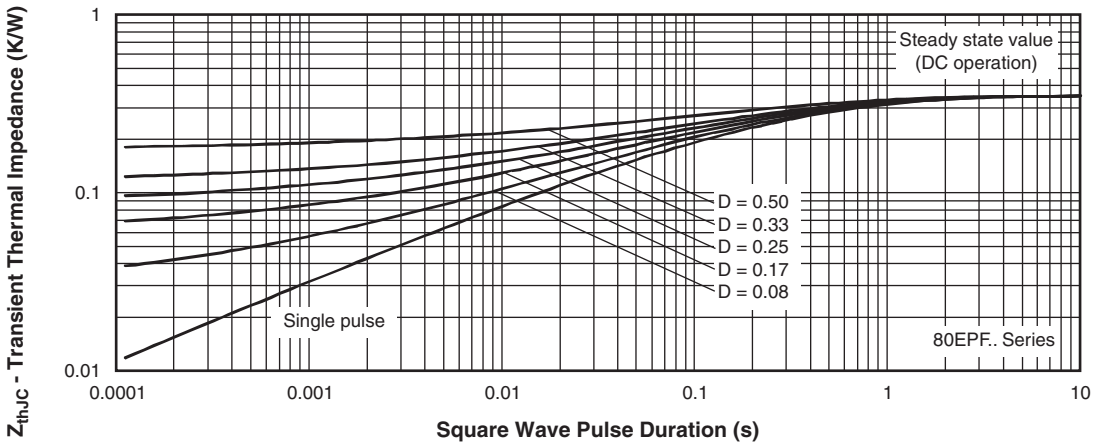
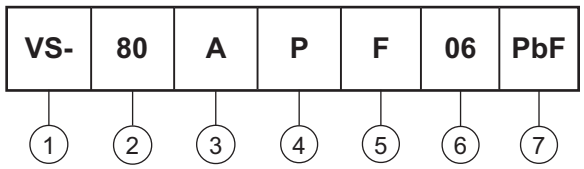


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (80 = 80 A)

3 - Circuit configuration:
A = Single diode, 3 pins

4 - Package:
P = TO-247AC

5 - Type of silicon:
F = Fast recovery

6 - Voltage code x 100 = V_{RRM}
- 02 = 200 V
- 04 = 400 V
- 06 = 600 V

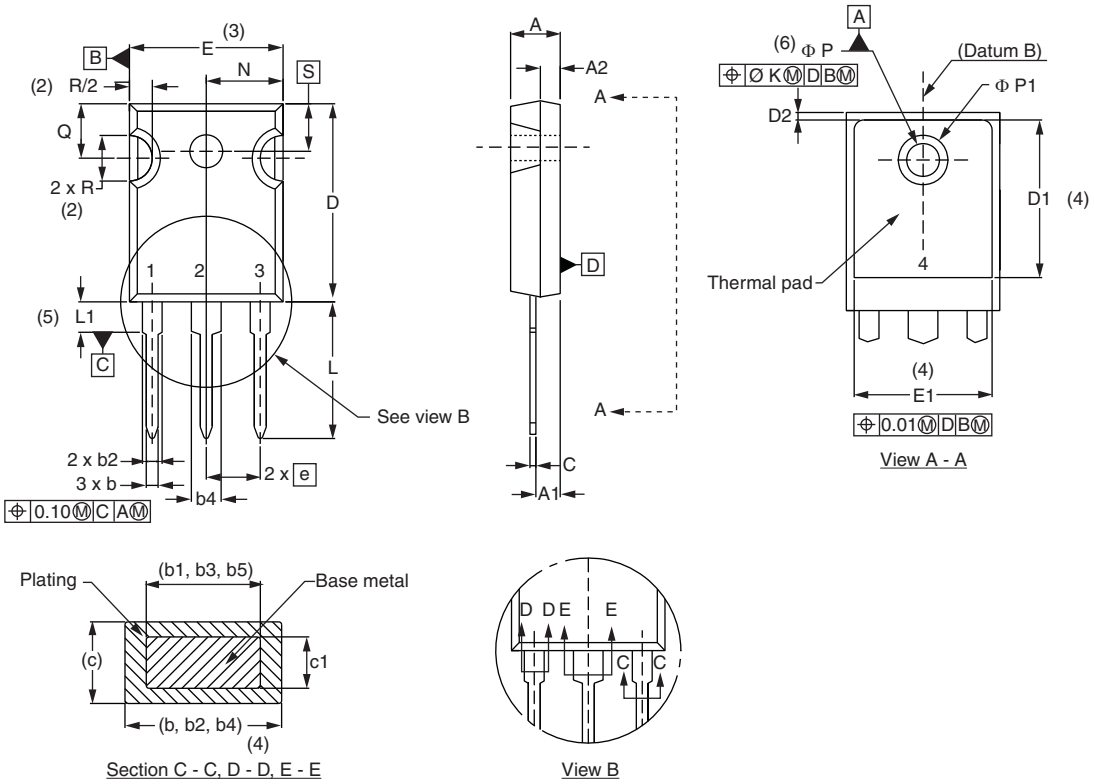
7 - Environmental digit:
- PbF = Lead (Pb)-free and RoHS compliant
- -M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)			
PREFERRED P/N	**QUANTITY PER T/R**	**MINIMUM ORDER QUANTITY**	**PACKAGING DESCRIPTION**
VS-80APF02PbF	25	500	Antistatic plastic tubes
VS-80APF02-M3	25	500	Antistatic plastic tubes
VS-80APF04PbF	25	500	Antistatic plastic tubes
VS-80APF04-M3	25	500	Antistatic plastic tubes
VS-80APF06PbF	25	500	Antistatic plastic tubes
VS-80APF06-M3	25	500	Antistatic plastic tubes

LINKS TO RELATED DOCUMENTS		
Dimensions		www.vishay.com/doc?95542
Part marking information	TO-247AC PbF	www.vishay.com/doc?95226
	TO-247AC -M3	www.vishay.com/doc?95007

TO-247 - 50 mils L/F

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES		SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.				MIN.	MAX.	MIN.	MAX.	
A	4.65	5.31	0.183	0.209			D2	0.51	1.35	0.020	0.053	
A1	2.21	2.59	0.087	0.102			E	15.29	15.87	0.602	0.625	3
A2	1.17	1.37	0.046	0.054			E1	13.46	-	0.53	-	
b	0.99	1.40	0.039	0.055			e	5.46 BSC		0.215 BSC		
b1	0.99	1.35	0.039	0.053			Ø K	0.254		0.010		
b2	1.65	2.39	0.065	0.094			L	14.20	16.10	0.559	0.634	
b3	1.65	2.34	0.065	0.092			L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135			N	7.62 BSC		0.3		
b5	2.59	3.38	0.102	0.133			Ø P	3.56	3.66	0.14	0.144	
c	0.38	0.89	0.015	0.035			Ø P1	-	7.39	-	0.291	
c1	0.38	0.84	0.015	0.033			Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3		R	4.52	5.49	0.178	0.216	
D1	13.08	-	0.515	-	4		S	5.51 BSC		0.217 BSC		

Notes

(1) Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

(5) Lead finish uncontrolled in L1

(6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

(7) Outline conforms to JEDEC® outline TO-247 with exception of dimension c and Q

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